

P-Channel 30 V (D-S) MOSFET

PRODUCT SUMMARY

V_{DS} (V)	$R_{DS(on)}$ (Ω)	I_D (A)	Q_g (Typ.)
- 30	0.167 at $V_{GS} = - 10$ V	0.96	3.25
	0.188 at $V_{GS} = - 4.5$ V	0.90	
	0.244 at $V_{GS} = - 2.5$ V	0.79	

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

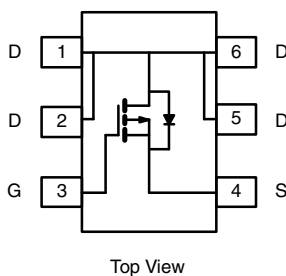


RoHS
COMPLIANT
HALOGEN
FREE

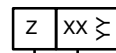
APPLICATIONS

- Load Switch for Portable Devices

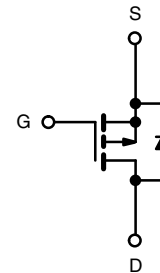
SC-89 (6-LEADS)



Marking Code



Lot Traceability
and Date Code
Part # Code



Ordering Information: Si1071X-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_A = 25$ °C, unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	- 30	V
Gate-Source Voltage	V_{GS}	± 12	
Continuous Drain Current ($T_J = 150$ °C)	$T_A = 25$ °C	I_D	A
	$T_A = 70$ °C	- 0.96 ^{b, c}	
Pulsed Drain Current	I_{DM}	- 8	
Continuous Source-Drain Diode Current	$T_A = 25$ °C	I_S	- 0.2 ^{b, c}
Maximum Power Dissipation ^a	$T_A = 25$ °C	P_D	0.236 ^{b, c}
	$T_A = 70$ °C		0.151 ^{b, c}
Operating Junction and Storage Temperature Range	T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^{a, b}	$t \leq 5$ s	R_{thJA}	440	°C/W
	Steady State		540	

Notes:

- Maximum under steady state conditions is 650 °C/W.
- Surface mounted on 1" x 1" FR4 board.
- $t = 5$ s.

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)						
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 30			V
V _{DS} Temperature Coefficient	ΔV _{DS} /T _J	I _D = - 250 μA		- 32.07		mV/°C
V _{GS(th)} Temperature Coefficient	ΔV _{GS(th)} /T _J			3.02		
Gate-Source Threshold Voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = - 250 μA	- 0.7		- 1.45	V
Gate-Source Leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 12 V			± 100	nA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 30 V, V _{GS} = 0 V			- 1	nA
		V _{DS} = - 30 V, V _{GS} = 0 V, T _J = 85 °C			- 10	μA
On-State Drain Current ^a	I _{D(on)}	V _{DS} ≥ 5 V, V _{GS} = - 10 V	- 8			A
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 10 V, I _D = - 0.96 A		0.139	0.167	Ω
		V _{GS} = - 4.5 V, I _D = - 0.9 A		0.147	0.177	
		V _{GS} = - 2.5 V, I _D = - 0.79 A		0.195	0.244	
Forward Transconductance	g _{fs}	V _{DS} = - 15 V, I _D = - 0.96 A		4.25		S
Dynamic ^b						
Input Capacitance	C _{iss}	V _{DS} = - 15 V, V _{GS} = 0 V, f = 1 MHz		315		pF
Output Capacitance	C _{oss}			60		
Reverse Transfer Capacitance	C _{rss}			45		
Total Gate Charge	Q _g	V _{DS} = - 15 V, V _{GS} = - 4.5 V, I _D = - 0.96 A		4.43	6.64	nC
Gate-Source Charge	Q _{gs}	V _{DS} = - 15 V, V _{GS} = - 10 V, I _D = - 0.96 A		8.87	13.3	
Gate-Drain Charge	Q _{gd}			0.83		
Gate Resistance	R _g			1.57		
Gate Resistance	R _g	f = 1 MHz		9.8	14.7	Ω
Turn-On Delay Time	t _{d(on)}	V _{DD} = - 15 V, R _L = 19.74 Ω I _D ≅ - 0.76 A, V _{GEN} = - 10 V, R _g = 1 Ω		3.8	5.7	ns
Rise Time	t _r			12	18	
Turn-Off DelayTime	t _{d(off)}			18	27	
Fall Time	t _f			7	10.5	
Turn-On Delay Time	t _{d(on)}	V _{DD} = - 15 V, R _L = 20.27 Ω I _D ≅ - 0.74 A, V _{GEN} = - 4.5 V, R _g = 1 Ω		13	20	
Rise Time	t _r			25	38	
Turn-Off DelayTime	t _{d(off)}			36	54	
Fall Time	t _f			14	21	
Drain-Source Body Diode Characteristics						
Pulse Diode Forward Current ^a	I _{SM}				8	A
Body Diode Voltage	V _{SD}	I _S = - 0.63 A		0.8	1.2	V
Body Diode Reverse Recovery Time	t _{rr}	I _F = - 0.7 A, dI/dt = 100 A/μs		12.7	19.05	nC
Body Diode Reverse Recovery	Q _{rr}			5.7	8.6	ns
Reverse Recovery Fall Time	t _a			8.9		
Reverse Recovery Rise Time	t _b			3.8		

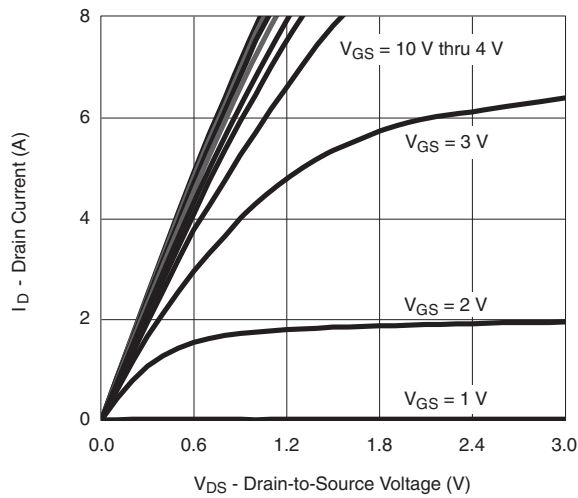
Notes:

a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.

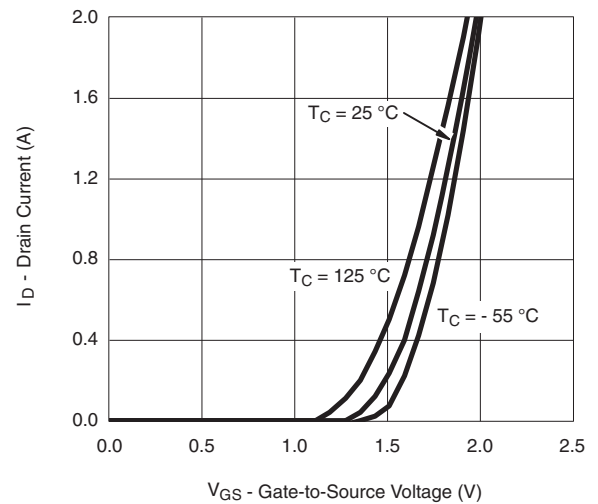
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

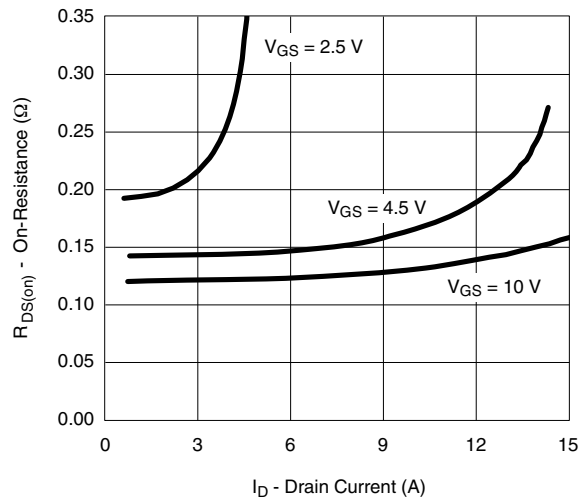
TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)



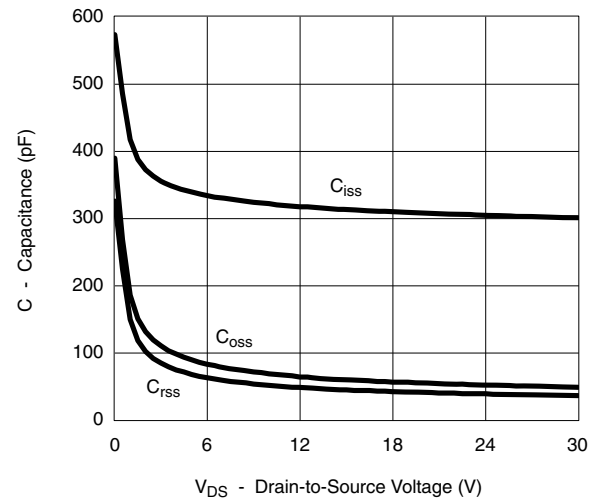
Output Characteristics



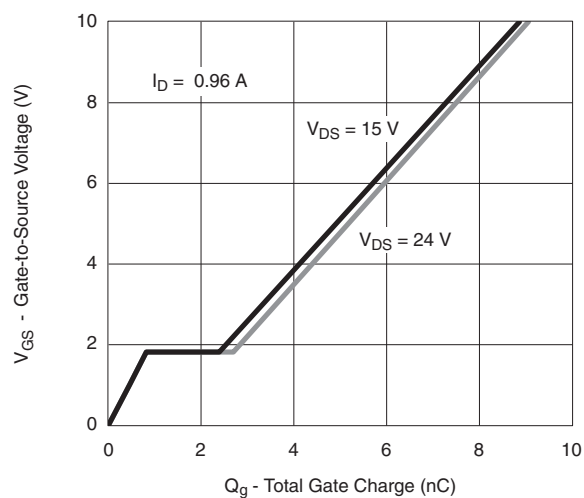
Transfer Characteristics Curves vs. Temp.



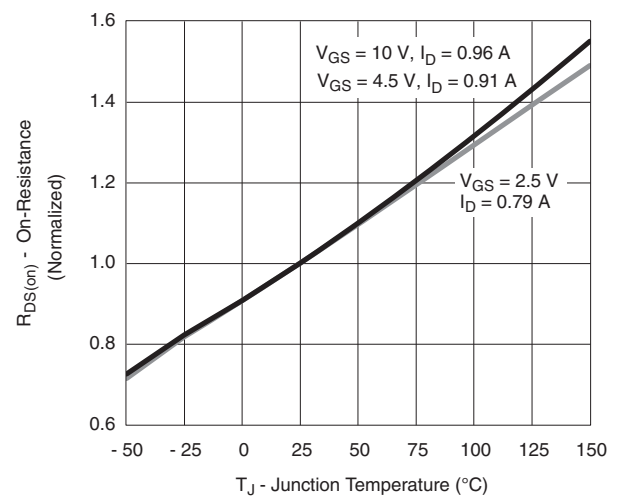
On-Resistance vs. Drain Current



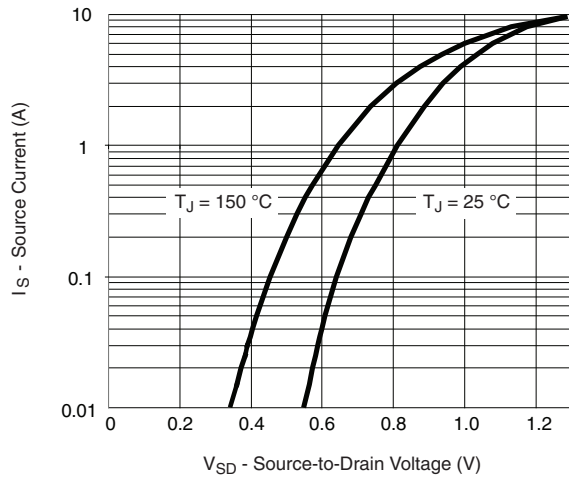
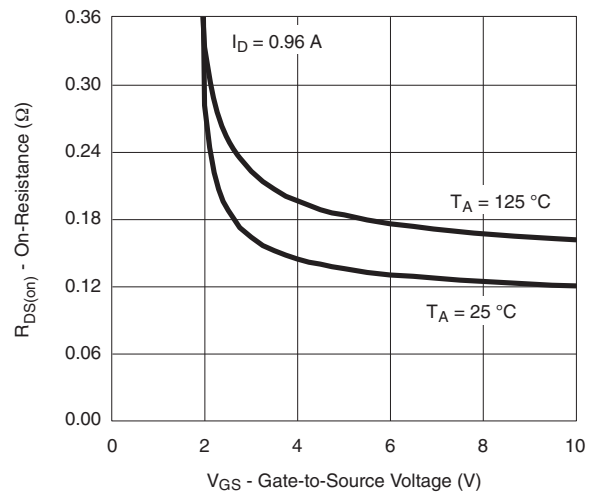
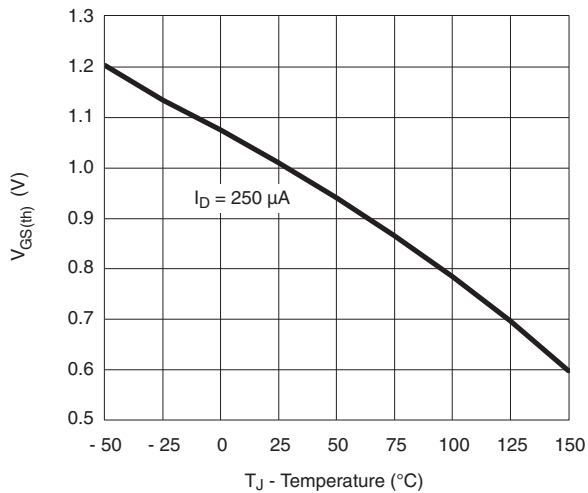
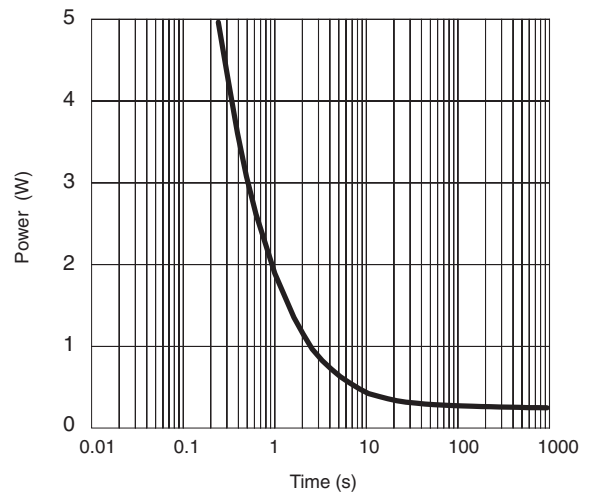
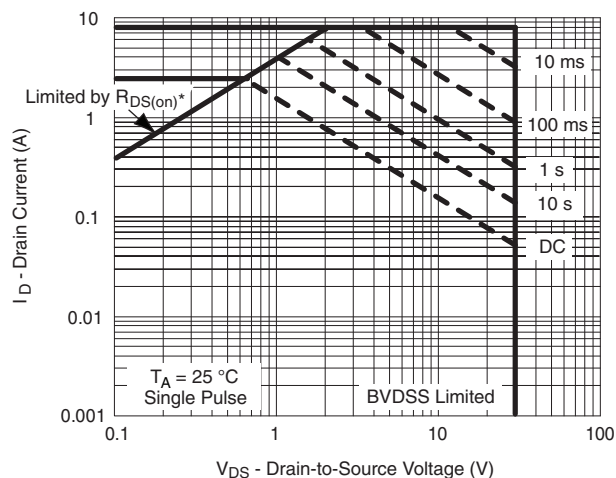
Capacitance



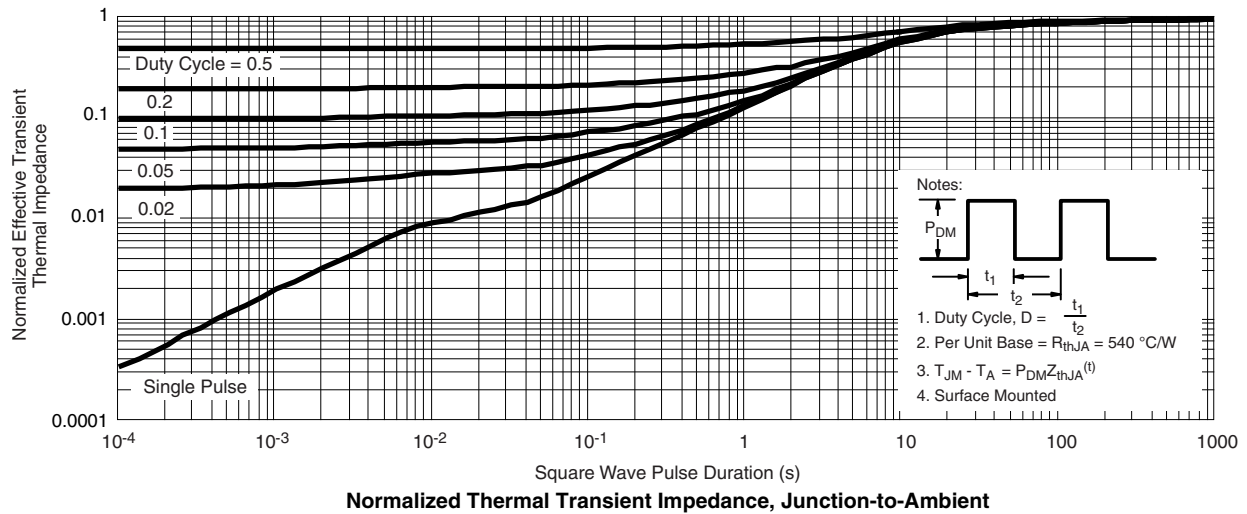
Gate Charge



On-Resistance vs. Junction Temperature

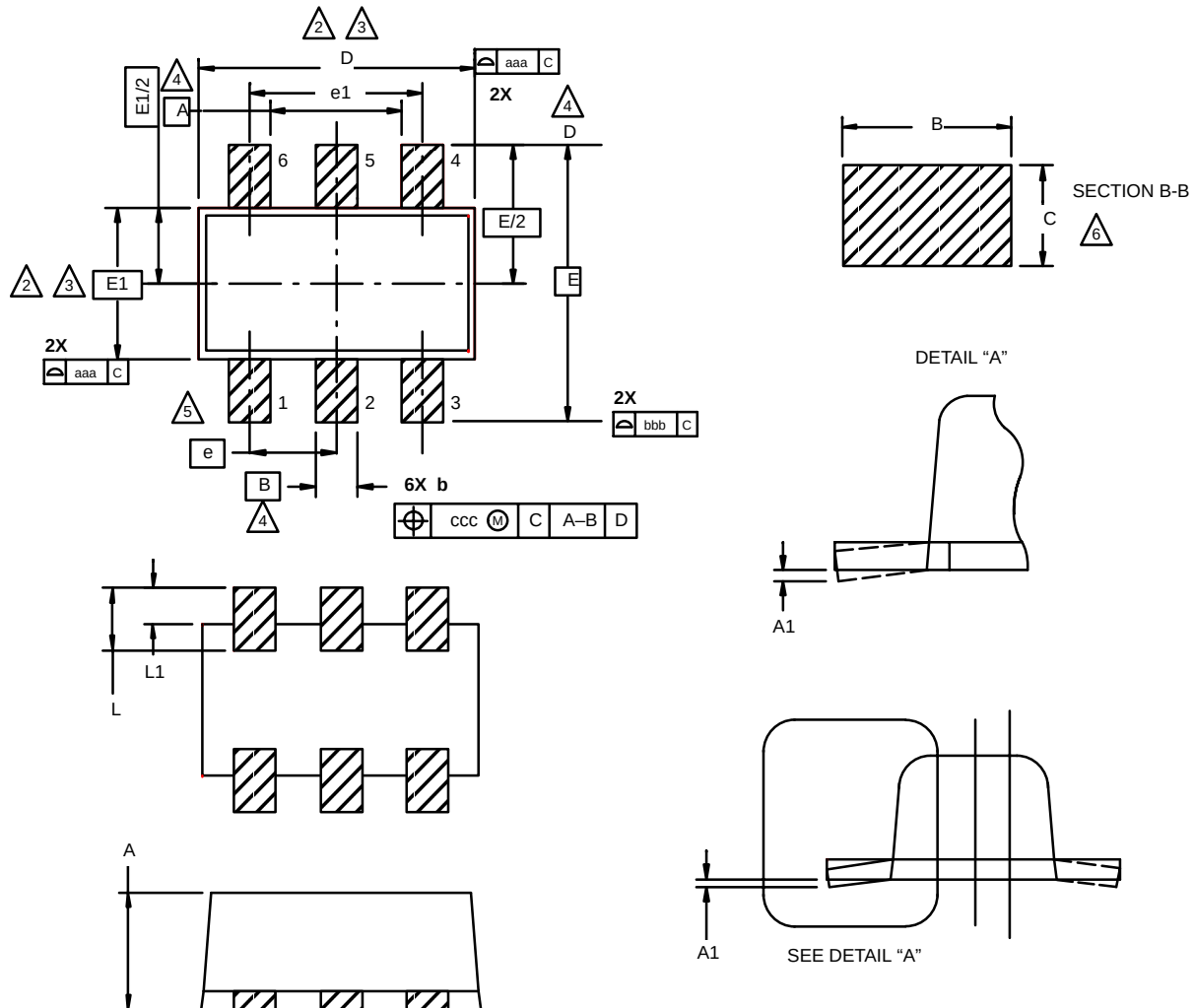
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)**Source-Drain Diode Forward Voltage****On-Resistance vs. Gate-to-Source Voltage****Threshold Voltage****Single Pulse Power*** $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified**Safe Operating Area, Junction-to-Ambient**

TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise noted)



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SC89: 6- LEADS (SOT-563F)



NOTES:

1. Dimensions in millimeters.

2 Dimension D does not include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.15 mm per dimension E1 does not include interlead flash or protrusion, interlead flash or protrusion shall not exceed 0.15 mm per side.

3 Dimensions D and E1 are determined at the outmost extremes of the plastic body exclusive of mold flash, the bar burrs, gate burrs and interlead flash, but including any mismatch between the top and the bottom of the plastic body.

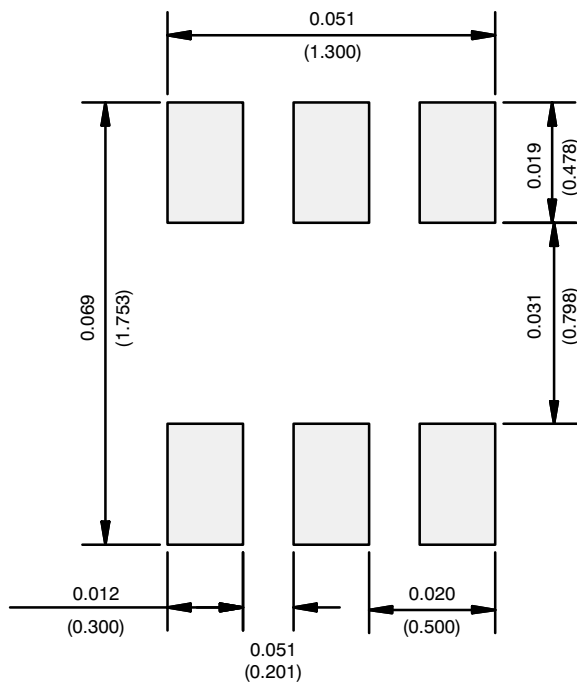
4 Datums A, B and D to be determined 0.10 mm from the lead tip.

5 Terminal numbers are shown for reference only.

6 These dimensions apply to the flat section of the lead between 0.08 mm and 0.15 mm from the lead tip.

Dim	MILLIMETERS		Note	Symbol	Tolerances Of Form And Position
	Min	Max			
A	0.56	0.60		aaa	0.10
A1	0.00	0.10		bbb	0.10
b	0.15	0.30		ccc	0.10
c	0.10	0.18			
D	1.50	1.70	2, 3		
E	1.55	1.70			
E1	1.20 BSC		2, 3		
e	0.50 BSC				
e1	1.00 BSC				
L	0.35 BSC				
L1	0.20 BSC				
ECN: E-00499—Rev. B, 02-Jul-01 DWG: 5880					

RECOMMENDED MINIMUM PADS FOR SC-89: 6-Lead



Recommended Minimum Pads
Dimensions in Inches/(mm)

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